RoHS TCR22-x Series

Littelfuse

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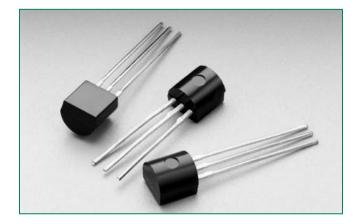
Main Features

Symbol

I_{T(RMS)}

I_{GT}

 $V_{\rm DRM}/V_{\rm RRM}$



Value

1.5

400 to 600

200

Unit

А

V µA

Description

Excellent unidirectional switches for phase control applications such as heating and motor speed controls.

Sensitive gate SCRs are easily triggered with microAmps of current as furnished by sense coils, proximity switches, and microprocessors.

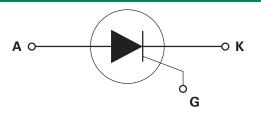
Features & Benefits

- RoHS compliant
- Glass passivated junctions
- Voltage capability up to 600 V
- Surge capability up to 20 A

Applications

Typical applications are capacitive discharge systems for strobe lights and gas engine ignition. Also controls for power tools, home/brown goods and white goods appliances.

Schematic Symbol



Symbol	Parameter	Test Conditions	Value	Unit	
I _{T(RMS)}	RMS on-state current	$T_c = 40^{\circ}C$	1.5	A	
	Deal, non ronstitive ourse ourset	single half cycle; f = 50Hz; T _J (initial) = 25°C	16	- A	
ITSM	Peak non-repetitive surge current	single half cycle; f = 60Hz; T _J (initial) = 25°C	20		
l²t	l²t Value for fusing	t _p = 8.3 ms	1.6	A²s	
di/dt	Critical rate of rise of on-state current	f = 60 Hz ; T _J = 110°C	50	A/µs	
I _{GM}	Peak gate current	T _J = 110°C	1	А	
P _{G(AV)}	Average gate power dissipation	T _J = 110°C	0.1	W	
T _{stg}	Storage temperature range		-40 to 150	°C	
Т,	Operating junction temperature range		-40 to 110	°C	

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Electrical Characteristics (T_J = 25°C, unless otherwise specified)

Symbol	Test Conditions	Value	Unit		
I _{gt}	V 6V/ P 100 0		MAX.	200	μA
V _{gt}	$V_{\rm D} = 6V; R_{\rm L} = 100 \Omega$		MAX.	0.8	V
-l / -l+	$V_{\rm D} = V_{\rm DRM}; R_{\rm GK} = 1 k \Omega$	400V	N 41N1	40	V/µs
dv/dt		600V	MIN.	30	
V _{gd}	$V_{\rm D} = V_{\rm DRM}; R_{\rm L} = 3.3 \text{ k}\Omega; T_{\rm J} = 110^{\circ}\text{C}$		MIN.	0.25	V
V _{grm}	$I_{gR} = 10 \mu A$		MIN.	6	V
I _H	I _T = 200mA (initial)		MAX.	5	mA
t _q	(1)		MAX.	50	μs
t _{gt}	$I_{g} = 2 \times I_{gT}$; PW = 15µs; $I_{T} = 3A$		TYP.	3.5	μs

(1) I_T =1A; t_p =50µs; dv/dt=5V/µs; di/dt=-10A/µs

Static Characteristics							
Symbol	Test Conditions Value Uni						
V _{TM}	I _T = 3	3A; t _p = 380 μs		1.5	V		
		T 25%C	400V		1		
I _{drm} / I _{rrm}	$V_{\text{DRM}} = V_{\text{RRM}}$	$T_{J} = 25^{\circ}C$	600V	MAX.	2	μA	
		T _J = 11	0°C		100		

Thermal Resistances

Symbol	Parameter	Value	Unit
R _{θ(J-C)}	Junction to case (AC)	50	°C/W
R _{θ(J-A)}	Junction to ambient	160	°C/W



1.5 Amp Sensitive SCRs

Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature

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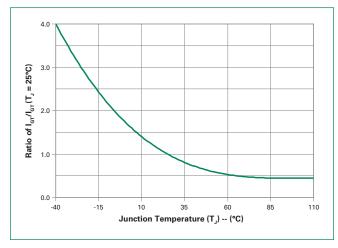
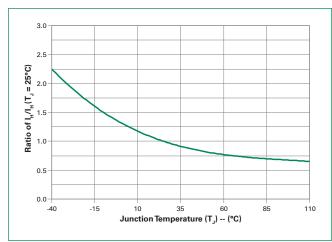




Figure 5: On-State Current vs. On-State

Voltage (Typical)



10 Instantaneous On-state Current (i_r) – Amps T_J = 25°C 8 6 4 2 0 0.7 0.8 0.9 1.0 1.1 1.2 1.3 1.4 1.5 1.6 Instantaneous On-state Voltage (v_T) – Volts

Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature

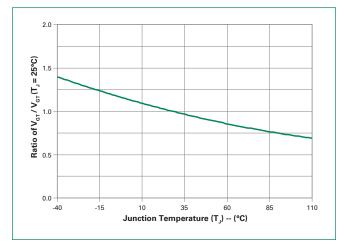


Figure 4: Normalized DC Latching Current vs. Junction Temperature

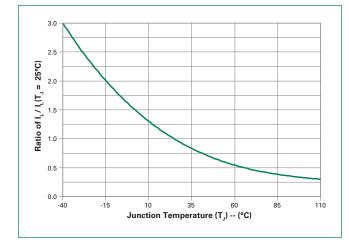
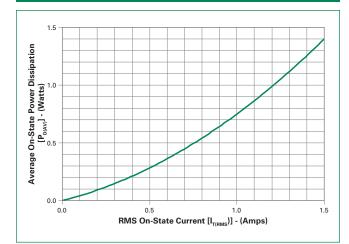


Figure 6: Power Dissipation (Typical) vs. RMS On-State Current



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Figure 7: Maximum Allowable Case Temperature vs. RMS On-State Current

115 Maximum Allowable Case Temperature (T_c) - °C 105 95 85 75 65 55 CURRENT WAVEFORM: Sinu idal 45 LOAD: Resistive or Inductive CONDUCTION ANGLE: 180° 35 0.0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8 RMS On-State Current $[I_{_{T(RMS)}}]$ - Amps

Figure 9: Maximum Allowable Ambient Temperature vs. RMS On-State Current

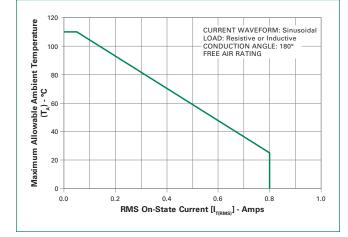


Figure 11: Peak Repetitive Capacitor Discharge Current

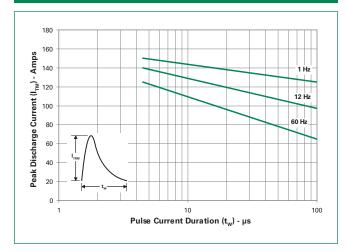
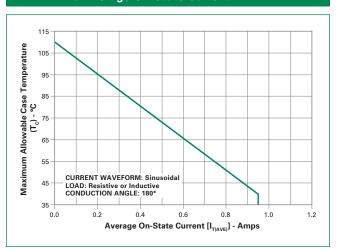


Figure 8: Maximum Allowable Case Temperature vs. Average On-State Current





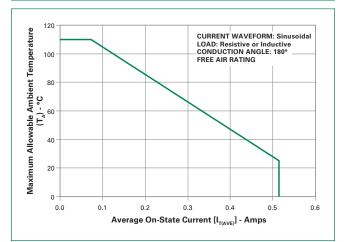
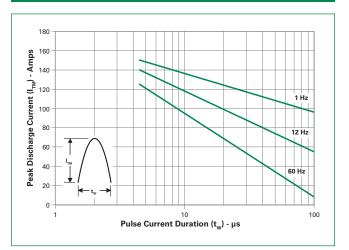


Figure 12: Peak Repetitive Sinusoidal Pulse Current





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Figure 13: Surge Peak On-State Current vs. Number of Cycles

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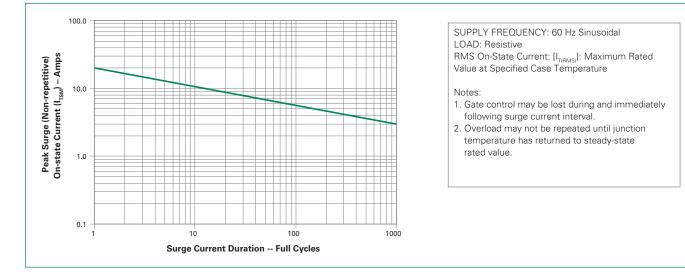
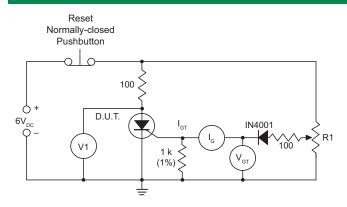


Figure 14: Simple Test Circuit for Gate Trigger Voltage and Current



Note: V1 - 0 V to 10 V dc meter $V_{GT} = 0$ V to 1 V dc meter $I_G = 0$ mA to 1 mA dc milliammeter R1 = 1 k potentiometer

To measure gate trigger voltage and current, raise gate voltage (V_{GT}) until meter reading V1 drops from 6 V to 1 V. Gate trigger voltage is the reading on $V_{\rm\scriptscriptstyle GT}$ just prior to V1 dropping. Gate trigger current I_{ct} Can be computed from the relationship

$$I_{GT} = I_{G} - \frac{V_{GT}}{1000} \text{Amps}$$

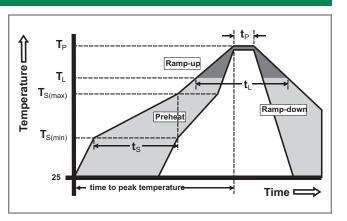
where I_{c} is reading (in amperes) on meter just prior to V1 dropping

Note: IGT may turn out to be a negative quantity (trigger current flows out from gate lead). If negative current occurs, I_{gT} value is not a valid reading. Remove 1 k resistor and use I_{g} as the more correct I_{gT} value. This will occur on 12 µA gate products.



Soldering Parameters

Reflow Co	ndition	Pb – Free assembly	
	-Temperature Min (T _{s(min)})	150°C	
Pre Heat	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 – 190 secs	
Average ra (T _L) to pea	amp up rate (LiquidusTemp) k	5°C/second max	
T _{S(max)} to T _L - Ramp-up Rate		5°C/second max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
nellow	-Temperature (t _L)	60 – 150 seconds	
PeakTemp	erature (T _P)	260 ^{+0/-5} °C	
Time with Temperatu	in 5°C of actual peak ıre (t _p)	20 – 40 seconds	
Ramp-dov	vn Rate	5°C/second max	
Time 25°C	to peakTemperature (T _P)	8 minutes Max.	
Do not exc	ceed	280°C	



Physical Specifications

Terminal Finish	100% Matt Tin-plated/Pb-free Solder Dipped	
Body Material	UL recognized epoxy meeting flammability classification 94V-0	
Lead Material	Copper Alloy	

Design Considerations

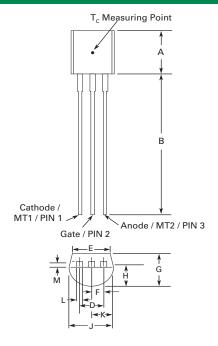
Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 110°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/ Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Thermal Shock	MIL-STD-750, M-1056 10 cycles; 0°C to 100°C; 5-min dwell- time at each temperature; 10 sec (max) transfer time between temperature
Autoclave	EIA / JEDEC, JESD22-A102 168 hours (121°C at 2 ATMs) and 100% R/H
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E



Dimensions – TO-92 (E Package)



Dimension	Inches		Millimeters		
Dimension	Min	Max	Min	Max	
А	0.176	0.196	4.47	4.98	
В	0.500		12.70		
D	0.095	0.105	2.41	2.67	
E	0.150		3.81		
F	0.046	0.054	1.16	1.37	
G	0.135	0.145	3.43	3.68	
Н	0.088	0.096	2.23	2.44	
J	0.176	0.186	4.47	4.73	
К	0.088	0.096	2.23	2.44	
L	0.013	0.019	0.33	0.48	
Μ	0.013	0.017	0.33	0.43	

All leads insulated from case. Case is electrically nonconductive.

Product Selector

Part Number	Voltage				Gate Sensitivity	Tuna	Deelverre
	400V	600V	800V	1000V		Туре	Package
TCR22-6	Х				200µA	Sensitive SCR	TO-92
TCR22-8		Х			200µA	Sensitive SCR	TO-92

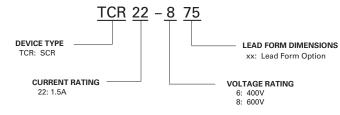
Note: x = Voltage

Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
TCR22-x	TCR22-x	0.19 g	Bulk	2000
TCR22-xRP	TCR22-x	0.19 g	Reel Pack	2000
TCR22-xAP	TCR22-x	0.19 g	Ammo Pack	2000

Note: x = Voltage

Part Numbering System



Part Marking System

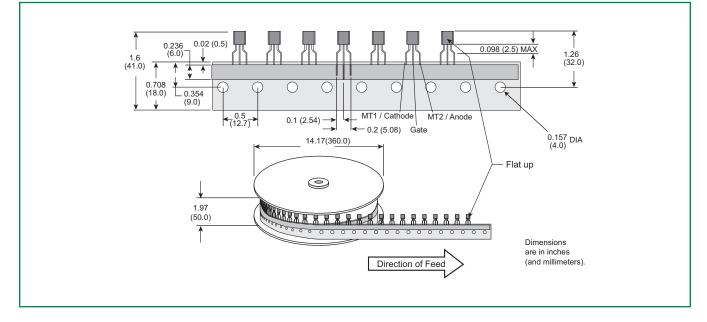
TO-92 (E Package)





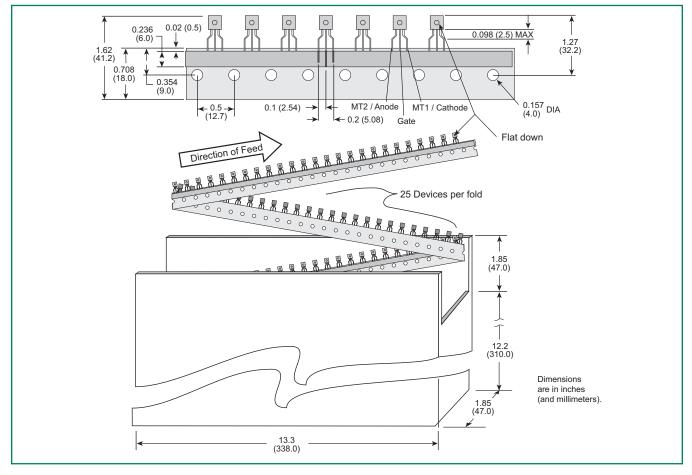
TO-92 (3-lead) Reel Pack (RP) Radial Leaded Specifications

Meets all EIA-468-B 1994 Standards



TO-92 (3-lead) Ammo Pack (AP) Radial Leaded Specifications

Meets all EIA-468-B 1994 Standards



单击下面可查看定价,库存,交付和生命周期等信息

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